



CMOS High Voltage Logic – CD4001B

Quad 2-Input NOR Gate Logic IC in bare die form

Rev 1.0
21/11/17

Description

The CD4001B is fabricated using a 3µm 15CMOS process. The device has equal source and sink current capabilities and conforms to standard B series output drive. Device outputs are buffered which improves transfer characteristics by providing very high gain. The device is capable of driving x2 low power TTL loads or x1 LSTTL load.

Features:

- High Input Voltage up to 20V
- Symmetrical Output Characteristics
- Max input current 1µA at 18°C over full Military Temperature Range
- Low Power TTL compatible
- Specified at 5V, 10V & 15V
- Direct drop-in replacement for obsolete components in long term programs.

Ordering Information

The following part suffixes apply:

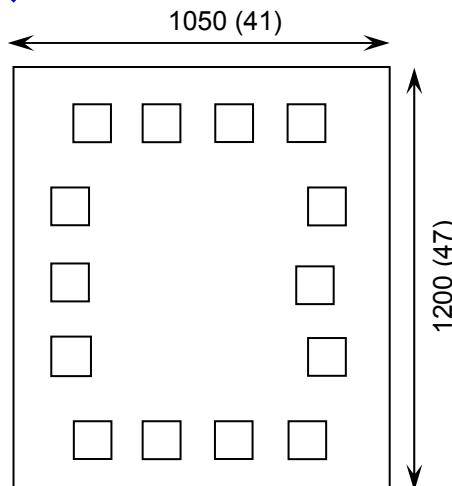
- No suffix - MIL-STD-883 /2010B Visual Inspection
- "H" - MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- "K" - MIL-STD-883 /2010A Visual Inspection (Space) + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com/quality/bare-die-lot-qualification

Die Dimensions in µm (mils)



Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- * Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <> 350µm(14 Mils) – On request
- Assembled into Ceramic Package – On request

Mechanical Specification

Die Size (Unsawn)	1050 x 1200 41 x 47	µm mils
Minimum Bond Pad Size	100 x 100 3.94 x 3.94	µm mils
Die Thickness	350 (± 20) 13.78 (± 0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µm	
Back Metal Composition	N/A – Bare Si	



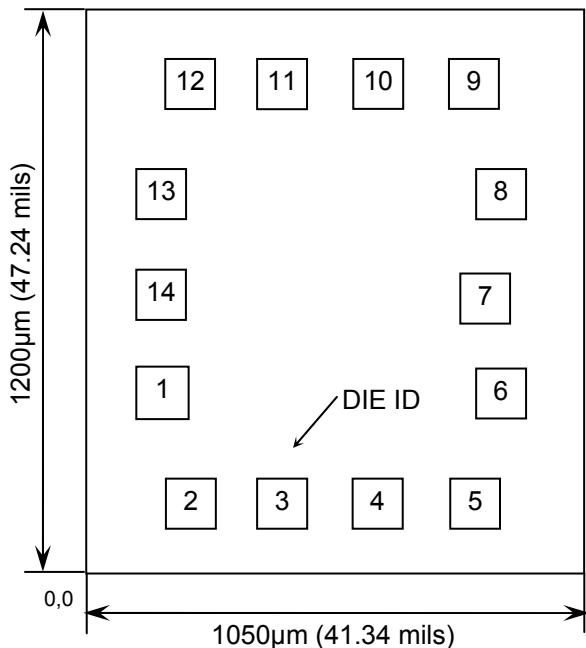


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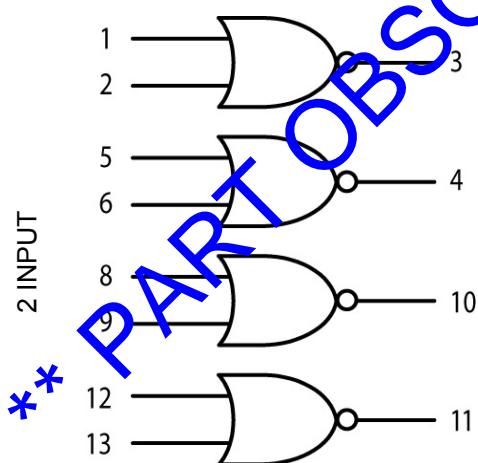
Pad Layout and Functions



PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	1A	0.108	0.340
2	1B	0.165	0.108
3	1Y	0.362	0.108
4	2A	0.566	0.108
5	2B	0.763	0.108
6	V _{SS}	0.820	0.340
7	3A	0.785	0.542
8	3B	0.820	0.759
9	3Y	0.763	0.991
10	4A	0.566	0.991
11	4B	0.362	0.991
12	4Y	0.165	0.991
13	V _{DD}	0.108	0.759
14	V _{DD}	0.108	0.548

CONNECT CHIP BACK TO V_{DD} OR FLOAT

Logic Diagram



Pad 14 = V_{DD}
Pad 7 = V_{SS}

Truth Table

INPUTS		OUTPUT
A	B	Y
L	L	H
L	H	L
H	L	L
H	H	L

H = High level (steady state)

L = Low level (steady state)



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Absolute Maximum Ratings¹

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to V _{SS})	V _{DD}	-0.5 to +20	V
DC Input or Output Voltage (Referenced to V _{SS})	V _{IN} , V _{OUT}	-0.5 to V _{DD} +0.5	V
Storage Temperature Range	T _{STG}	-65 to 150	°C
Input Current or Output Current (per Pad)	I _{IN} , I _{OUT}	±10	mA
Power Dissipation in Still Air ²	P _D	750	mW

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

Recommended Operating Conditions³ (Voltages referenced to V_{SS})

PARAMETER	SYMBOL	MIN	MAX	UNITS
Supply Voltage	V _{DD}	3.0	18	V
DC Input Voltage, Output Voltage	V _{IN} , V _{OUT}	0	V _{DD}	V
Operating Temperature Range	T _J	-55	+125	°C

3. This device contains protection circuitry against damage due to high static voltages or electric fields. However, any voltage higher than maximum rated voltages to this high-impedance circuit should be avoided. For proper operation, V_{IN} & V_{OUT} should be constrained to the range V_{SS} ≤ (V_{IN} or V_{OUT}) ≤ V_{DD}. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

DC Electrical Characteristics (Voltages referenced to V_{SS})

PARAMETER	SYMBOL	V _{DD}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Minimum High-Level Input Voltage	V _{IH}	5V	V _{OUT} = 0.5V	3.5	3.5	3.5	V
		10V	V _{OUT} = 1.0V	7	7	7	
		15V	V _{OUT} = 1.5V	11	11	11	
Maximum Low-Level Input Voltage	V _{IL}	5V	V _{OUT} = 0.5V or V _{DD} - 0.5V	1.5	1.5	1.5	V
		10V	V _{OUT} = 0.5V or V _{DD} - 0.5V	3	3	3	
		15V	V _{OUT} = 0.5V or V _{DD} - 0.5V	4	4	4	
Minimum High-Level Output Voltage	V _{OH}	5V	V _{IN} = 0 or V _{DD}	4.95	4.95	4.95	V
		10V		9.95	9.95	9.95	
		15V		14.95	14.95	14.95	
Maximum Low-Level Output Voltage	V _{OL}	5V	V _{IN} = V _{DD} or 0	0.05	0.05	0.05	V
		10V		0.05	0.05	0.05	
		15V		0.05	0.05	0.05	
Maximum Input Leakage Current	I _{IN}	18V	V _{IN} = V _{DD} or V _{SS}	±0.1	±0.1	±1.0	µA
Maximum Quiescent Supply Current	I _{DD}	5V	V _{IN} = V _{DD} or V _{SS} I _{OUT} = 0µA	0.25	7.5	7.5	µA
		10V		0.5	15	15	
		15V		1.0	30	30	
		20V		5.0	150	150	





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DC Electrical Characteristics Continued (Voltages referenced to V_{SS})

PARAMETER	SYMBOL	V _{DD}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Minimum Output Low (Sink) Current	I _{OL}	5V	V _{IN} = V _{DD} or V _{SS} V _{OL} = 0.4V	0.51	0.42	0.36	mA
		10V	V _{IN} = V _{DD} or V _{SS} V _{OL} = 0.5V	1.3	1.1	0.3	
		15V	V _{IN} = V _{DD} or V _{SS} V _{OL} = 1.5V	3.4	2.8	2.4	
Minimum Output High (Source) Current	I _{OH}	5V	V _{IN} = V _{DD} or V _{SS} V _{OH} = 2.5V	-1.6	-1.2	-1.15	mA
		5V	V _{IN} = V _{DD} or V _{SS} V _{OH} = 4.6V	-0.51	-0.42	-0.36	
		10V	V _{IN} = V _{DD} or V _{SS} V _{OH} = 9.5V	-1.3	-1.1	-0.9	
		15V	V _{IN} = V _{DD} or V _{SS} V _{OH} = 13.5V	-3.4	-2.8	-2.4	

4. -55°C ≤ T_J ≤ +125°C

AC Electrical Characteristics⁵

PARAMETER	SYMBOL	V _{DD}	CONDITIONS	TYPICAL		LIMITS		UNITS
				-55°C to 25°C	≤ 85°C	≤ 125°C	≤ 125°C	
Propagation Delay, Input A or B to Output Y (Figure 1)	t _{PLH} , t _{PHL}	5V	C _L = 50pF, R _L = 200kΩ t _r = t _f = 20ns	125	250	500	ns	
		10V		60	100	200		
		15V		45	80	160		
Output Transition Time, Any Output (Figure 1)	t _{THL} , t _{TRH}	5V	C _L = 50pF, R _L = 200kΩ t _r = t _f = 20ns	100	200	400	ns	
		10V		50	100	500		
		15V		40	80	160		
Input Capacitance	C _{IN}	-	C _L = 50pF, R _L = 200kΩ t _r = t _f = 20ns	5	7.5	7.5	pF	

5. Not production tested in die form, characterized by chip design and tested in package.

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